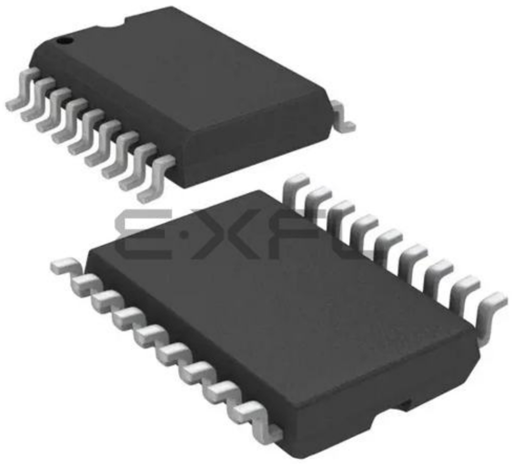

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	4MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	13
Program Memory Size	1.75KB (1K x 14)
Program Memory Type	FLASH
EEPROM Size	64 x 8
RAM Size	68 x 8
Voltage - Supply (Vcc/Vdd)	2V ~ 5.5V
Data Converters	-
Oscillator Type	External
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	18-SOIC (0.295", 7.50mm Width)
Supplier Device Package	18-SOIC
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16lf84a-04-so

TABLE 1-1: PIC16F84A PINOUT DESCRIPTION

Pin Name	PDIP No.	SOIC No.	SSOP No.	I/O/P Type	Buffer Type	Description
OSC1/CLKIN	16	16	18	I	ST/CMOS(3)	Oscillator crystal input/external clock source input.
OSC2/CLKOUT	15	15	19	O	—	Oscillator crystal output. Connects to crystal or resonator in Crystal Oscillator mode. In RC mode, OSC2 pin outputs CLKOUT, which has 1/4 the frequency of OSC1 and denotes the instruction cycle rate.
$\overline{MCLR}$	4	4	4	I/P	ST	Master Clear (Reset) input/programming voltage input. This pin is an active low RESET to the device.
						PORTA is a bi-directional I/O port.
RA0	17	17	19	I/O	TTL	
RA1	18	18	20	I/O	TTL	
RA2	1	1	1	I/O	TTL	
RA3	2	2	2	I/O	TTL	
RA4/T0CKI	3	3	3	I/O	ST	Can also be selected to be the clock input to the TMR0 timer/counter. Output is open drain type.
						PORTB is a bi-directional I/O port. PORTB can be software programmed for internal weak pull-up on all inputs.
RB0/INT	6	6	7	I/O	TTL/ST(1)	RB0/INT can also be selected as an external interrupt pin.
RB1	7	7	8	I/O	TTL	
RB2	8	8	9	I/O	TTL	
RB3	9	9	10	I/O	TTL	
RB4	10	10	11	I/O	TTL	Interrupt-on-change pin.
RB5	11	11	12	I/O	TTL	Interrupt-on-change pin.
RB6	12	12	13	I/O	TTL/ST(2)	Interrupt-on-change pin. Serial programming clock.
RB7	13	13	14	I/O	TTL/ST(2)	Interrupt-on-change pin. Serial programming data.
VSS	5	5	5,6	P	—	Ground reference for logic and I/O pins.
VDD	14	14	15,16	P	—	Positive supply for logic and I/O pins.

Legend: I= input O = Output I/O = Input/Output P = Power
— = Not used TTL = TTL input ST = Schmitt Trigger input

Note 1: This buffer is a Schmitt Trigger input when configured as the external interrupt.
2: This buffer is a Schmitt Trigger input when used in Serial Programming mode.
3: This buffer is a Schmitt Trigger input when configured in RC oscillator mode and a CMOS input otherwise.

3.1 Reading the EEPROM Data Memory

To read a data memory location, the user must write the address to the EEADR register and then set control bit RD (EECON1<0>). The data is available, in the very next cycle, in the EEDATA register; therefore, it can be read in the next instruction. EEDATA will hold this value until another read or until it is written to by the user (during a write operation).

EXAMPLE 3-1: DATA EEPROM READ

```
BCF     STATUS, RP0  ; Bank 0
MOVLW   CONFIG_ADDR  ;
MOVWF   EEADR        ; Address to read
BSF     STATUS, RP0  ; Bank 1
BSF     EECON1, RD   ; EE Read
BCF     STATUS, RP0  ; Bank 0
MOVF    EEDATA, W    ; W = EEDATA
```

3.2 Writing to the EEPROM Data Memory

To write an EEPROM data location, the user must first write the address to the EEADR register and the data to the EEDATA register. Then the user must follow a specific sequence to initiate the write for each byte.

EXAMPLE 3-2: DATA EEPROM WRITE

```
        BSF     STATUS, RP0   ; Bank 1
        BCF     INTCON, GIE   ; Disable INTs.
        BSF     EECON1, WREN  ; Enable Write
        MOVLW   55h           ;
Required Sequence:
        MOVWF   EECON2        ; Write 55h
        MOVLW   AAh           ;
        MOVWF   EECON2        ; Write AAh
        BSF     EECON1,WR     ; Set WR bit
                              ;   begin write
        BSF     INTCON, GIE   ; Enable INTs.
```

The write will not initiate if the above sequence is not exactly followed (write 55h to EECON2, write AAh to EECON2, then set WR bit) for each byte. We strongly recommend that interrupts be disabled during this code segment.

Additionally, the WREN bit in EECON1 must be set to enable write. This mechanism prevents accidental writes to data EEPROM due to errant (unexpected) code execution (i.e., lost programs). The user should keep the WREN bit clear at all times, except when updating EEPROM. The WREN bit is not cleared by hardware.

After a write sequence has been initiated, clearing the WREN bit will not affect this write cycle. The WR bit will be inhibited from being set unless the WREN bit is set.

At the completion of the write cycle, the WR bit is cleared in hardware and the EE Write Complete Interrupt Flag bit (EEIF) is set. The user can either enable this interrupt or poll this bit. EEIF must be cleared by software.

3.3 Write Verify

Depending on the application, good programming practice may dictate that the value written to the Data EEPROM should be verified (Example 3-3) to the desired value to be written. This should be used in applications where an EEPROM bit will be stressed near the specification limit.

Generally, the EEPROM write failure will be a bit which was written as a '0', but reads back as a '1' (due to leakage off the bit).

EXAMPLE 3-3: WRITE VERIFY

```
      BCF   STATUS,RP0  ; Bank 0
      :                 ; Any code
      :                 ; can go here
      MOVF  EEDATA,W    ; Must be in Bank 0
      BSF   STATUS,RP0  ; Bank 1
READ
      BSF   EECON1, RD  ; YES, Read the
                        ; value written
      BCF   STATUS, RP0 ; Bank 0
                        ;
                        ; Is the value written
                        ; (in W reg) and
                        ; read (in EEDATA)
                        ; the same?
                        ;
      SUBWF EEDATA, W   ;
      BTFSS STATUS, Z   ; Is difference 0?
      GOTO  WRITE_ERR   ; NO, Write error
```

TABLE 3-1: REGISTERS/BITS ASSOCIATED WITH DATA EEPROM

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-on Reset	Value on all other RESETS
08h	EEDATA	EEPROM Data Register								xxxx xxxx	uuuu uuuu
09h	EEADR	EEPROM Address Register								xxxx xxxx	uuuu uuuu
88h	EECON1	—	—	—	EEIF	WRERR	WREN	WR	RD	---0 x000	---0 q000
89h	EECON2	EEPROM Control Register 2								---- ----	---- ----

Legend: x = unknown, u = unchanged, - = unimplemented, read as '0', q = value depends upon condition.
Shaded cells are not used by data EEPROM.

TABLE 4-1: PORTA FUNCTIONS

Name	Bit0	Buffer Type	Function
RA0	bit0	TTL	Input/output
RA1	bit1	TTL	Input/output
RA2	bit2	TTL	Input/output
RA3	bit3	TTL	Input/output
RA4/T0CKI	bit4	ST	Input/output or external clock input for TMR0. Output is open drain type.

Legend: TTL = TTL input, ST = Schmitt Trigger input

TABLE 4-2: SUMMARY OF REGISTERS ASSOCIATED WITH PORTA

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-on Reset	Value on all other RESETS
05h	PORTA	—	—	—	RA4/T0CKI	RA3	RA2	RA1	RA0	---x xxxx	---u uuuu
85h	TRISA	—	—	—	TRISA4	TRISA3	TRISA2	TRISA1	TRISA0	---1 1111	---1 1111

Legend: x = unknown, u = unchanged, - = unimplemented, read as '0'. Shaded cells are unimplemented, read as '0'.

6.2 Oscillator Configurations

6.2.1 OSCILLATOR TYPES

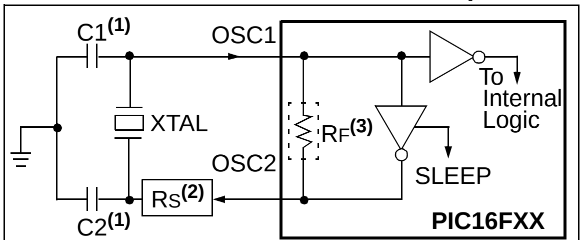
The PIC16F84A can be operated in four different oscillator modes. The user can program two configuration bits (FOSC1 and FOSC0) to select one of these four modes:

- LP Low Power Crystal
- XT Crystal/Resonator
- HS High Speed Crystal/Resonator
- RC Resistor/Capacitor

6.2.2 CRYSTAL OSCILLATOR/CERAMIC RESONATORS

In XT, LP, or HS modes, a crystal or ceramic resonator is connected to the OSC1/CLKIN and OSC2/CLKOUT pins to establish oscillation (Figure 6-1).

FIGURE 6-1: CRYSTAL/CERAMIC RESONATOR OPERATION (HS, XT OR LP OSC CONFIGURATION)



Note 1: See Table 6-1 for recommended values of C1 and C2.

2: A series resistor (Rs) may be required for AT strip cut crystals.

The PIC16F84A oscillator design requires the use of a parallel cut crystal. Use of a series cut crystal may give a frequency out of the crystal manufacturers specifications. When in XT, LP, or HS modes, the device can have an external clock source to drive the OSC1/CLKIN pin (Figure 6-2).

FIGURE 6-2: EXTERNAL CLOCK INPUT OPERATION (HS, XT OR LP OSC CONFIGURATION)

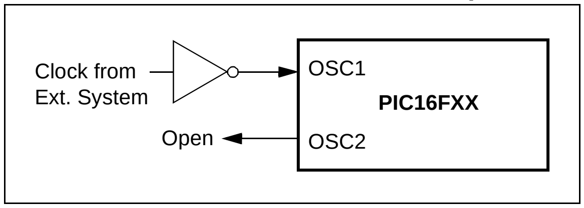


TABLE 6-1: CAPACITOR SELECTION FOR CERAMIC RESONATORS

Ranges Tested:			
Mode	**Freq**	**OSC1/C1**	**OSC2/C2**
XT	455 kHz	47 - 100 pF	47 - 100 pF
	2.0 MHz	15 - 33 pF	15 - 33 pF
	4.0 MHz	15 - 33 pF	15 - 33 pF
HS	8.0 MHz	15 - 33 pF	15 - 33 pF
	10.0 MHz	15 - 33 pF	15 - 33 pF

Note: Recommended values of C1 and C2 are identical to the ranges tested in this table. Higher capacitance increases the stability of the oscillator, but also increases the start-up time. These values are for design guidance only. Since each resonator has its own characteristics, the user should consult the resonator manufacturer for the appropriate values of external components.

Note: When using resonators with frequencies above 3.5 MHz, the use of HS mode rather than XT mode, is recommended. HS mode may be used at any VDD for which the controller is rated.

6.3 RESET

The PIC16F84A differentiates between various kinds of RESET:

- Power-on Reset (POR)
- $\overline{\text{MCLR}}$ during normal operation
- $\overline{\text{MCLR}}$ during SLEEP
- WDT Reset (during normal operation)
- WDT Wake-up (during SLEEP)

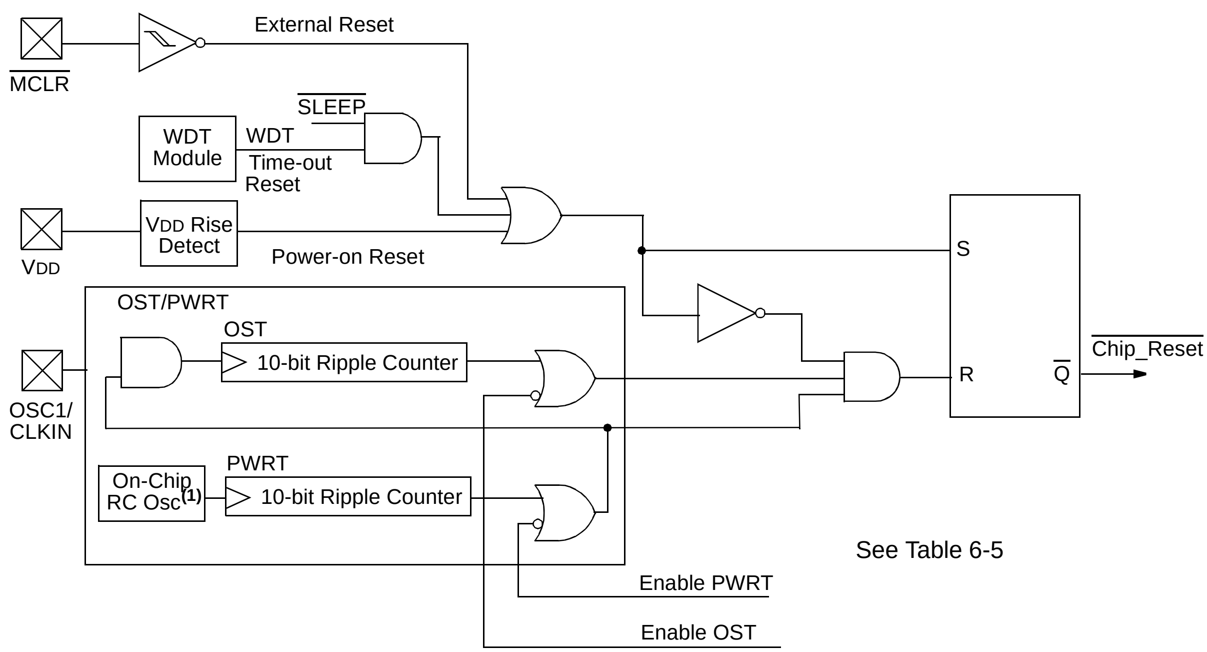
Figure 6-4 shows a simplified block diagram of the On-Chip RESET Circuit. The $\overline{\text{MCLR}}$ Reset path has a noise filter to ignore small pulses. The electrical specifications state the pulse width requirements for the $\overline{\text{MCLR}}$ pin.

Some registers are not affected in any RESET condition; their status is unknown on a POR and unchanged in any other RESET. Most other registers are reset to a "RESET state" on POR, $\overline{\text{MCLR}}$ or WDT Reset during normal operation and on $\overline{\text{MCLR}}$ during SLEEP. They are not affected by a WDT Reset during SLEEP, since this RESET is viewed as the resumption of normal operation.

Table 6-3 gives a description of RESET conditions for the program counter (PC) and the STATUS register. Table 6-4 gives a full description of RESET states for all registers.

The $\overline{\text{TO}}$ and $\overline{\text{PD}}$ bits are set or cleared differently in different RESET situations (Section 6.7). These bits are used in software to determine the nature of the RESET.

FIGURE 6-4: SIMPLIFIED BLOCK DIAGRAM OF ON-CHIP RESET CIRCUIT



Note 1: This is a separate oscillator from the RC oscillator of the CLKIN pin.
2: See Table 6-5.

TABLE 6-3: RESET CONDITION FOR PROGRAM COUNTER AND THE STATUS REGISTER

Condition	Program Counter	STATUS Register
Power-on Reset	000h	`0001 1xxx`
$\overline{\text{MCLR}}$ during normal operation	000h	`000u uuuu`
$\overline{\text{MCLR}}$ during SLEEP	000h	`0001 0uuu`
WDT Reset (during normal operation)	000h	`0000 1uuu`
WDT Wake-up	PC + 1	`uuu0 0uuu`
Interrupt wake-up from SLEEP	PC + 1(1)	`uuu1 0uuu`

Legend: u = unchanged, x = unknown
Note 1: When the wake-up is due to an interrupt and the GIE bit is set, the PC is loaded with the interrupt vector (0004h).

6.4 Power-on Reset (POR)

A Power-on Reset pulse is generated on-chip when VDD rise is detected (in the range of 1.2V - 1.7V). To take advantage of the POR, just tie the $\overline{\text{MCLR}}$ pin directly (or through a resistor) to VDD. This will eliminate external RC components usually needed to create Power-on Reset. A minimum rise time for VDD must be met for this to operate properly. See Electrical Specifications for details.

When the device starts normal operation (exits the RESET condition), device operating parameters (voltage, frequency, temperature, etc.) must be met to ensure operation. If these conditions are not met, the device must be held in RESET until the operating conditions are met.

For additional information, refer to Application Note AN607, "*Power-up Trouble Shooting*."

The POR circuit does not produce an internal RESET when VDD declines.

6.5 Power-up Timer (PWRT)

The Power-up Timer (PWRT) provides a fixed 72 ms nominal time-out (TPWRT) from POR (Figures 6-6 through 6-9). The Power-up Timer operates on an internal RC oscillator. The chip is kept in RESET as long as the PWRT is active. The PWRT delay allows the VDD to rise to an acceptable level (possible exception shown in Figure 6-9).

A configuration bit, $\overline{\text{PWRTE}}$, can enable/disable the PWRT. See Register 6-1 for the operation of the $\overline{\text{PWRTE}}$ bit for a particular device.

The power-up time delay TPWRT will vary from chip to chip due to VDD, temperature, and process variation. See DC parameters for details.

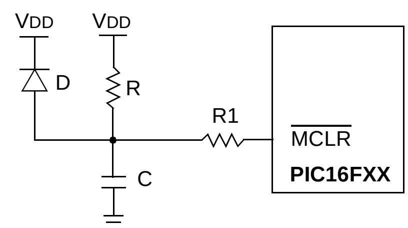
6.6 Oscillator Start-up Timer (OST)

The Oscillator Start-up Timer (OST) provides a 1024 oscillator cycle delay (from OSC1 input) after the PWRT delay ends (Figure 6-6, Figure 6-7, Figure 6-8 and Figure 6-9). This ensures the crystal oscillator or resonator has started and stabilized.

The OST time-out (TOST) is invoked only for XT, LP and HS modes and only on Power-on Reset or wake-up from SLEEP.

When VDD rises very slowly, it is possible that the TPWRT time-out and TOST time-out will expire before VDD has reached its final value. In this case (Figure 6-9), an external Power-on Reset circuit may be necessary (Figure 6-5).

FIGURE 6-5: EXTERNAL POWER-ON RESET CIRCUIT (FOR SLOW VDD POWER-UP)



Note 1: External Power-on Reset circuit is required only if VDD power-up rate is too slow. The diode D helps discharge the capacitor quickly when VDD powers down.

2: R < 40 kΩ is recommended to make sure that voltage drop across R does not exceed 0.2V (max leakage current spec on $\overline{\text{MCLR}}$ pin is 5 μA). A larger voltage drop will degrade VIH level on the $\overline{\text{MCLR}}$ pin.

3: R1 = 100Ω to 1 kΩ will limit any current flowing into $\overline{\text{MCLR}}$ from external capacitor C, in the event of a $\overline{\text{MCLR}}$ pin breakdown due to ESD or EOS.

FIGURE 6-6: TIME-OUT SEQUENCE ON POWER-UP ($\overline{\text{MCLR}}$ NOT TIED TO V_{DD}): CASE 1

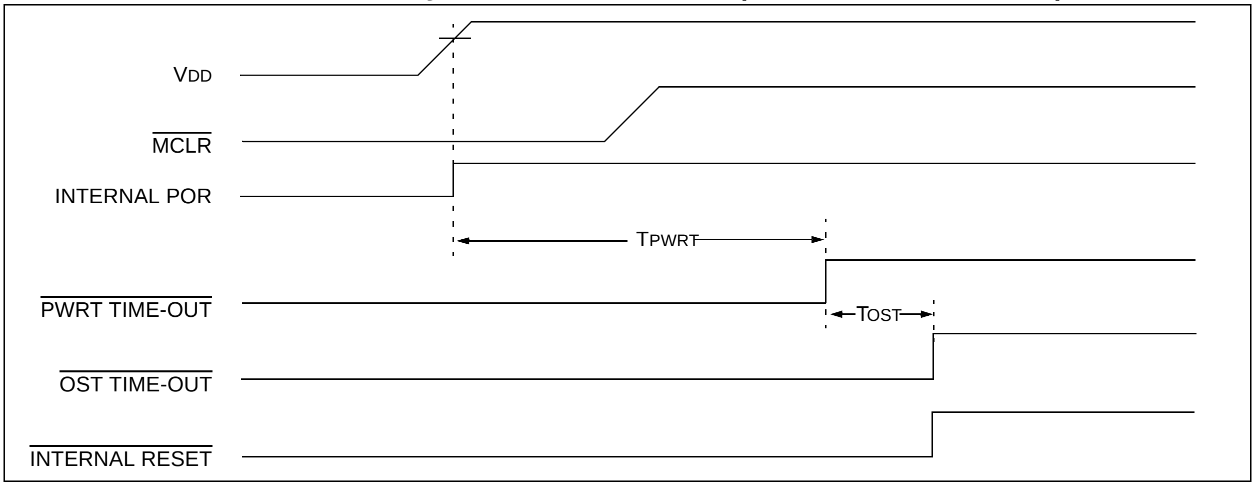


FIGURE 6-7: TIME-OUT SEQUENCE ON POWER-UP ($\overline{\text{MCLR}}$ NOT TIED TO V_{DD}): CASE 2

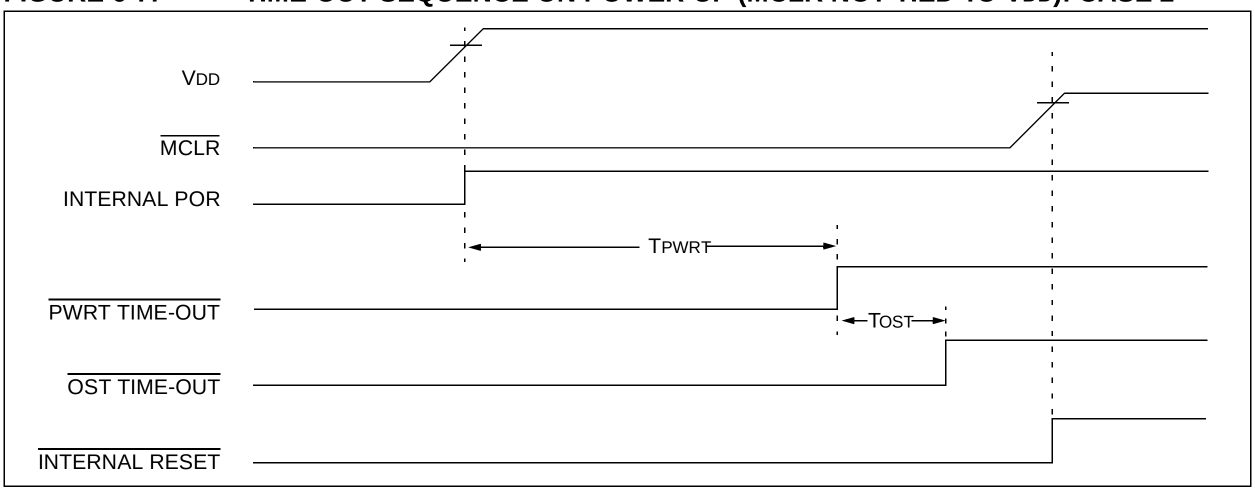
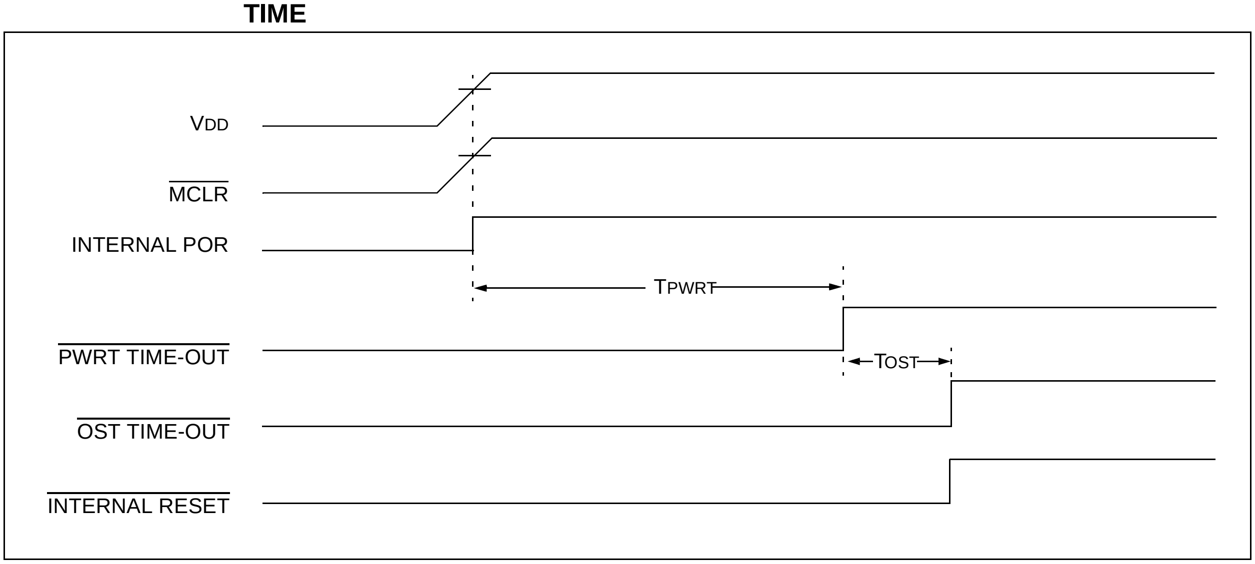


FIGURE 6-8: TIME-OUT SEQUENCE ON POWER-UP ($\overline{\text{MCLR}}$ TIED TO V_{DD}): FAST V_{DD} RISE TIME



6.9 Context Saving During Interrupts

During an interrupt, only the return PC value is saved on the stack. Typically, users wish to save key register values during an interrupt (e.g., W register and STATUS register). This is implemented in software.

The code in Example 6-1 stores and restores the STATUS and W register's values. The user defined registers, W_TEMP and STATUS_TEMP are the temporary storage locations for the W and STATUS registers values.

Example 6-1 does the following:

a) Stores the W register.
b) Stores the STATUS register in STATUS_TEMP.
c) Executes the Interrupt Service Routine code.
d) Restores the STATUS (and bank select bit) register.
e) Restores the W register.

EXAMPLE 6-1: SAVING STATUS AND W REGISTERS IN RAM

```
PUSH    MOVWF   W_TEMP              ; Copy W to TEMP register,
        SWAPF   STATUS,     W       ; Swap status to be saved into W
        MOVWF   STATUS_TEMP         ; Save status to STATUS_TEMP register
ISR     :                           :
        :                           ; Interrupt Service Routine
        :                           ; should configure Bank as required
        :                           ;
POP     SWAPF   STATUS_TEMP,W       ; Swap nibbles in STATUS_TEMP register
                                    ; and place result into W
        MOVWF   STATUS              ; Move W into STATUS register
                                    ; (sets bank to original state)
        SWAPF   W_TEMP,     F       ; Swap nibbles in W_TEMP and place result in W_TEMP
        SWAPF   W_TEMP,     W       ; Swap nibbles in W_TEMP and place result into W
```

6.10 Watchdog Timer (WDT)

The Watchdog Timer is a free running On-Chip RC Oscillator which does not require any external components. This RC oscillator is separate from the RC oscillator of the OSC1/CLKIN pin. That means that the WDT will run even if the clock on the OSC1/CLKIN and OSC2/CLKOUT pins of the device has been stopped, for example, by execution of a SLEEP instruction. During normal operation, a WDT time-out generates a device RESET. If the device is in SLEEP mode, a WDT wake-up causes the device to wake-up and continue with normal operation. The WDT can be permanently disabled by programming configuration bit WDTE as a '0' (Section 6.1).

6.10.1 WDT PERIOD

The WDT has a nominal time-out period of 18 ms, (with no prescaler). The time-out periods vary with temperature, V_{DD} and process variations from part to part (see DC specs). If longer time-out periods are desired, a prescaler with a division ratio of up to 1:128 can be assigned to the WDT under software control by writing to the OPTION_REG register. Thus, time-out periods up to 2.3 seconds can be realized.

The CLRWDT and SLEEP instructions clear the WDT and the postscaler (if assigned to the WDT) and prevent it from timing out and generating a device RESET condition.

The $\overline{TO}$ bit in the STATUS register will be cleared upon a WDT time-out.

NOTES:

BTFSC	Bit Test, Skip if Clear
Syntax:	[*label*] BTFSC f,b
Operands:	$0 \le f \le 127$ $0 \le b \le 7$
Operation:	skip if (f<b>) = 0
Status Affected:	None
Description:	If bit 'b' in register 'f' is '1', the next instruction is executed. If bit 'b' in register 'f' is '0', the next instruction is discarded, and a `NOP` is executed instead, making this a $2T_{CY}$ instruction.

CALL	Call Subroutine
Syntax:	[*label*] CALL k
Operands:	$0 \le k \le 2047$
Operation:	(PC)+ 1→ TOS, k → PC<10:0>, (PCLATH<4:3>) → PC<12:11>
Status Affected:	None
Description:	Call Subroutine. First, return address (PC+1) is pushed onto the stack. The eleven-bit immediate address is loaded into PC bits <10:0>. The upper bits of the PC are loaded from PCLATH. `CALL` is a two-cycle instruction.

CLRF	Clear f
Syntax:	[*label*] CLRF f
Operands:	$0 \le f \le 127$
Operation:	00h → (f) 1 → Z
Status Affected:	Z
Description:	The contents of register 'f' are cleared and the Z bit is set.

CLRW	Clear W
Syntax:	[*label*] CLRW
Operands:	None
Operation:	00h → (W) 1 → Z
Status Affected:	Z
Description:	W register is cleared. Zero bit (Z) is set.

CLRWDT	Clear Watchdog Timer
Syntax:	[*label*] CLRWDT
Operands:	None
Operation:	00h → WDT 0 → WDT prescaler, 1 → $\overline{TO}$ 1 → $\overline{PD}$
Status Affected:	$\overline{TO}$, $\overline{PD}$
Description:	`CLRWDT` instruction resets the Watchdog Timer. It also resets the prescaler of the WDT. Status bits $\overline{TO}$ and $\overline{PD}$ are set.

COMF	Complement f
Syntax:	[*label*] COMF f,d
Operands:	$0 \le f \le 127$ $d \in [0,1]$
Operation:	$(\bar{f})$ → (destination)
Status Affected:	Z
Description:	The contents of register 'f' are complemented. If 'd' is 0, the result is stored in W. If 'd' is 1, the result is stored back in register 'f'.

DECF	Decrement f
Syntax:	[*label*] DECF f,d
Operands:	$0 \le f \le 127$ $d \in [0,1]$
Operation:	(f) - 1 → (destination)
Status Affected:	Z
Description:	Decrement register 'f'. If 'd' is 0, the result is stored in the W register. If 'd' is 1, the result is stored back in register 'f'.

XORLW	Exclusive OR Literal with W
Syntax:	[*label*] XORLW k
Operands:	$0 \leq k \leq 255$
Operation:	(W) .XOR. k $\rightarrow$ (W)
Status Affected:	Z
Description:	The contents of the W register are XOR'ed with the eight-bit literal 'k'. The result is placed in the W register.

XORWF	Exclusive OR W with f
Syntax:	[*label*] XORWF f,d
Operands:	$0 \leq f \leq 127$ $d \in [0,1]$
Operation:	(W) .XOR. (f) $\rightarrow$ (destination)
Status Affected:	Z
Description:	Exclusive OR the contents of the W register with register 'f'. If 'd' is 0, the result is stored in the W register. If 'd' is 1, the result is stored back in register 'f'.

9.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Ambient temperature under bias .... -55°C to +125°C

Storage temperature .... -65°C to +150°C

Voltage on any pin with respect to V_{SS} (except V_{DD}, $\overline{MCLR}$, and RA4) .... -0.3V to (V_{DD} + 0.3V)

Voltage on V_{DD} with respect to V_{SS} .... -0.3 to +7.5V

Voltage on $\overline{MCLR}$ with respect to V_{SS} **(1)** .... -0.3 to +14V

Voltage on RA4 with respect to V_{SS} .... -0.3 to +8.5V

Total power dissipation **(2)** .... 800 mW

Maximum current out of V_{SS} pin .... 150 mA

Maximum current into V_{DD} pin .... 100 mA

Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{DD}$) .... ± 20 mA

Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{DD}$) .... ± 20 mA

Maximum output current sunk by any I/O pin .... 25 mA

Maximum output current sourced by any I/O pin .... 25 mA

Maximum current sunk by PORTA .... 80 mA

Maximum current sourced by PORTA .... 50 mA

Maximum current sunk by PORTB .... 150 mA

Maximum current sourced by PORTB .... 100 mA

Note 1: Voltage spikes below V_{SS} at the $\overline{MCLR}$ pin, inducing currents greater than 80 mA, may cause latch-up. Thus, a series resistor of 50-100Ω should be used when applying a "low" level to the $\overline{MCLR}$ pin rather than pulling this pin directly to V_{SS}.

2: Power dissipation is calculated as follows: $Pdis = V_{DD} \times \{I_{DD} - \sum I_{OH}\} + \sum \{(V_{DD}-V_{OH}) \times I_{OH}\} + \sum(V_{Ol} \times I_{OL})$.

† NOTICE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

FIGURE 10-3: TYPICAL IDD vs. FOSC OVER VDD (XT MODE, 25°C)

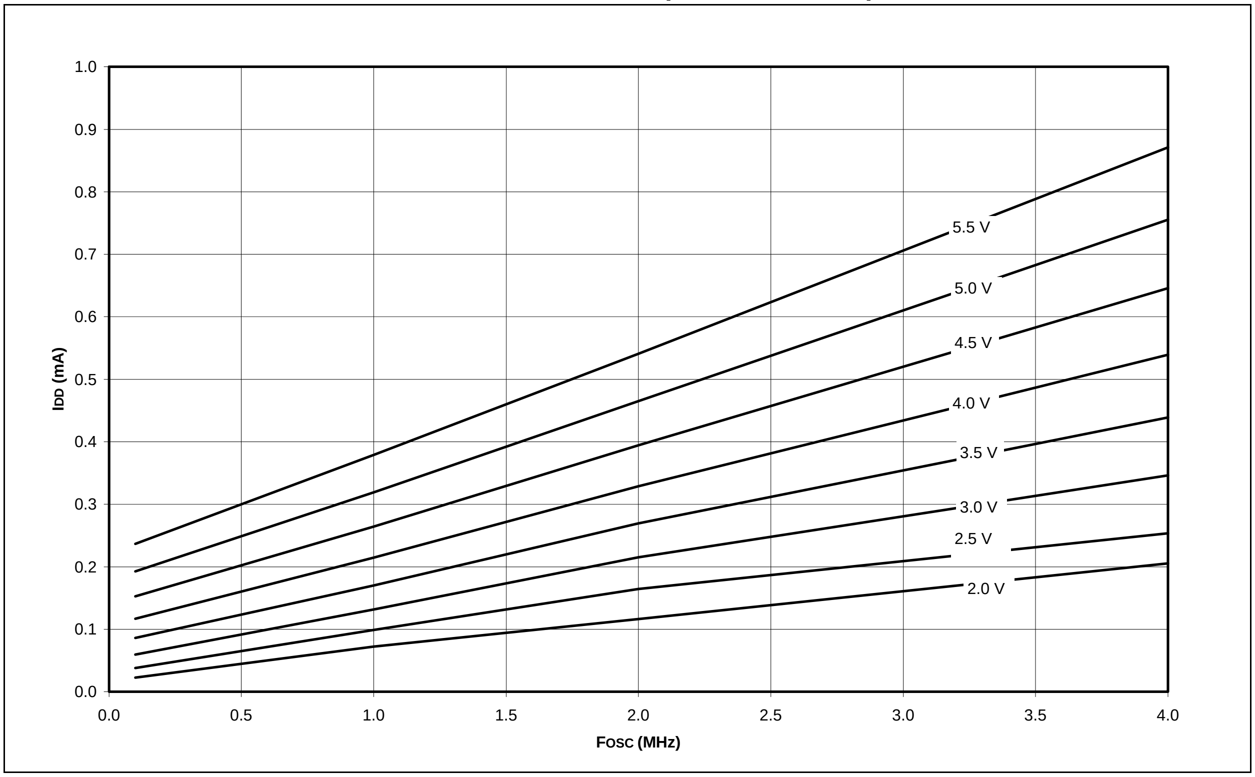


FIGURE 10-4: MAXIMUM IDD vs. FOSC OVER VDD (XT MODE, -40° TO +125°C)

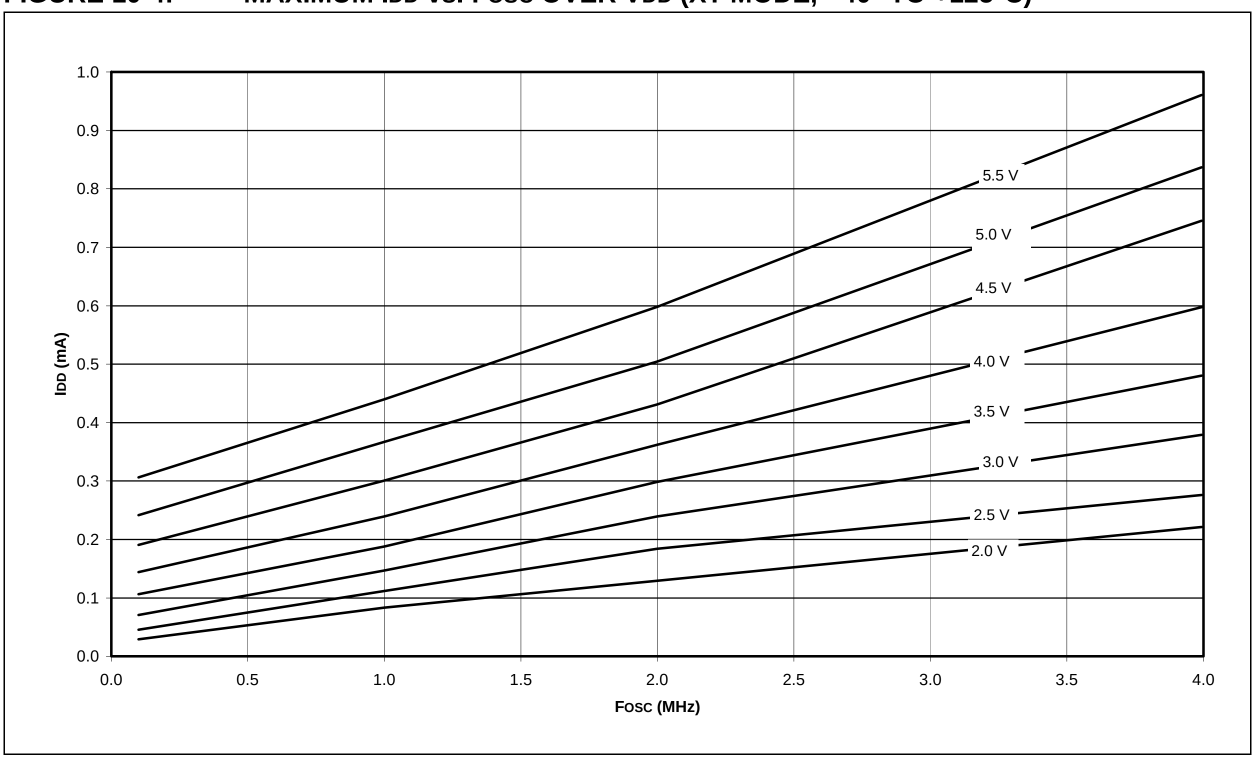


FIGURE 10-5: TYPICAL IDD vs. FOSC OVER VDD (LP MODE, 25°C)

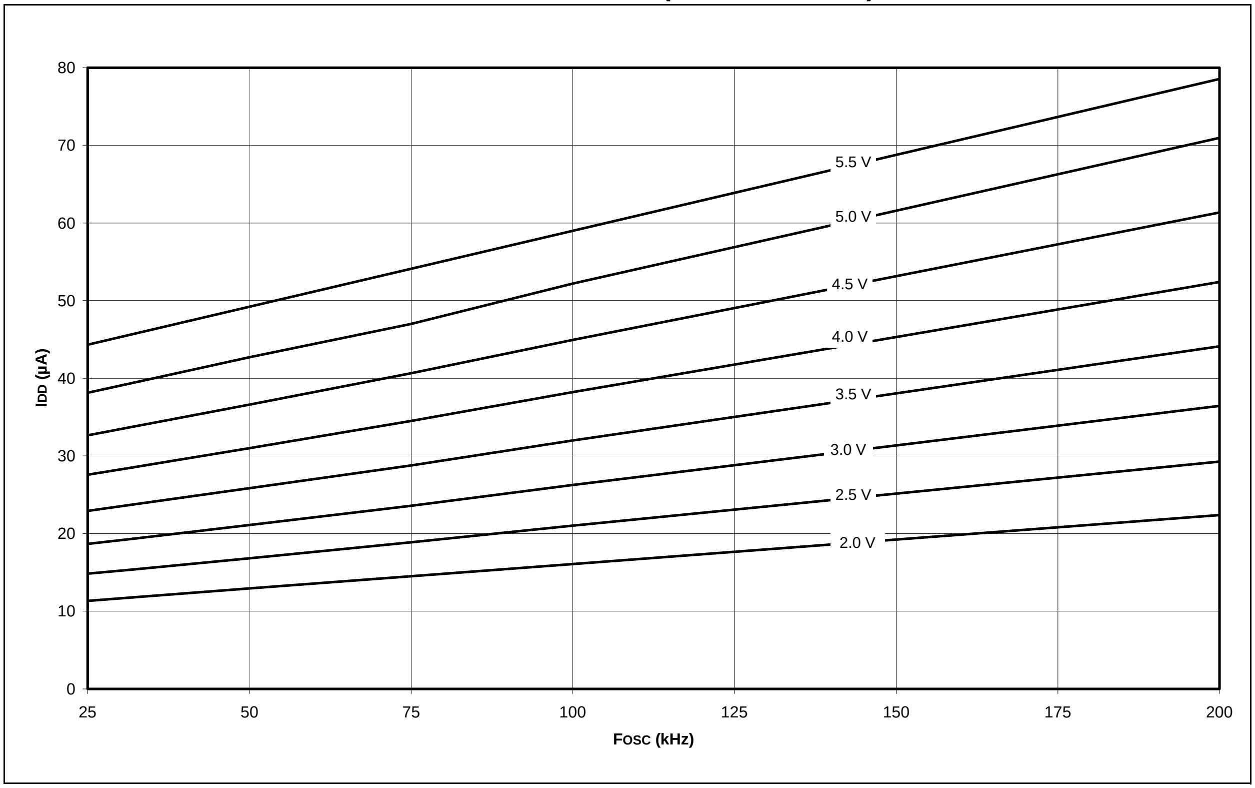


FIGURE 10-6: MAXIMUM IDD vs. FOSC OVER VDD (LP MODE, -40° TO +125°C)

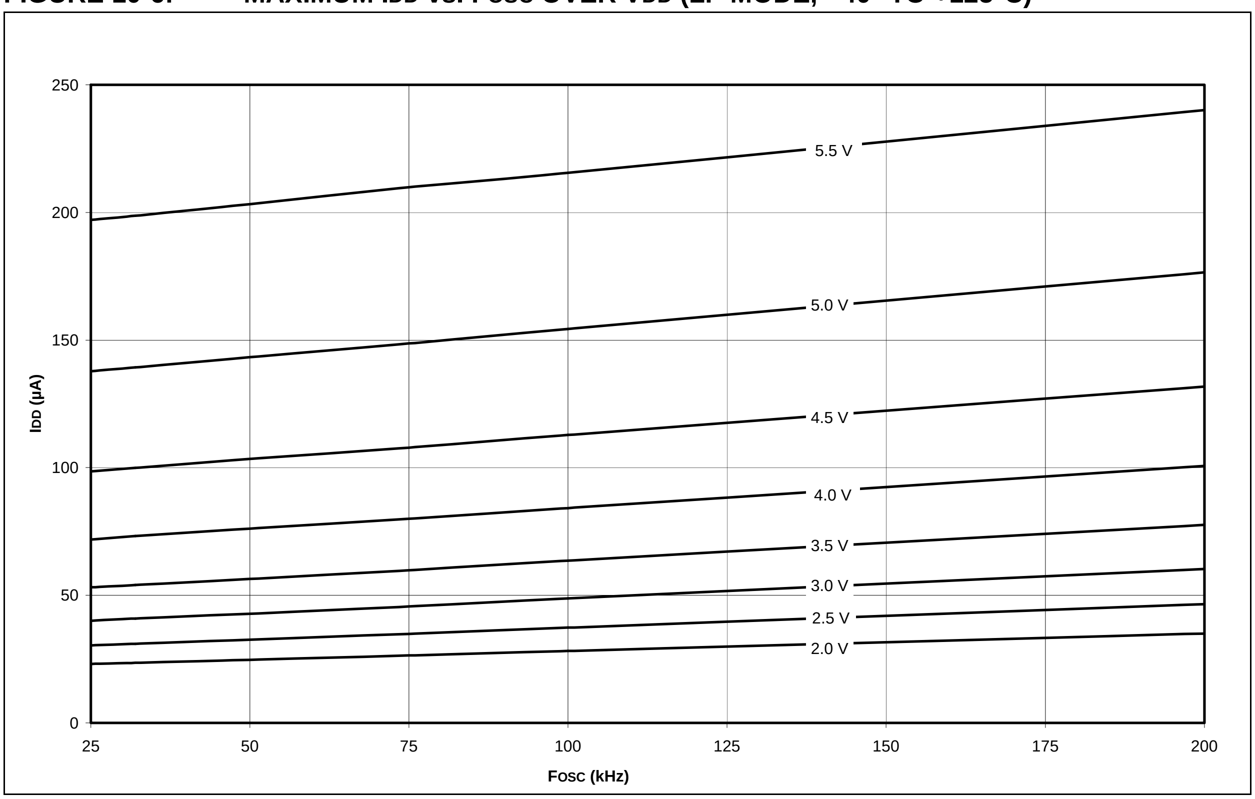


FIGURE 10-7: AVERAGE FOSC vs. VDD FOR R (RC MODE, C = 22 pF, 25°C)

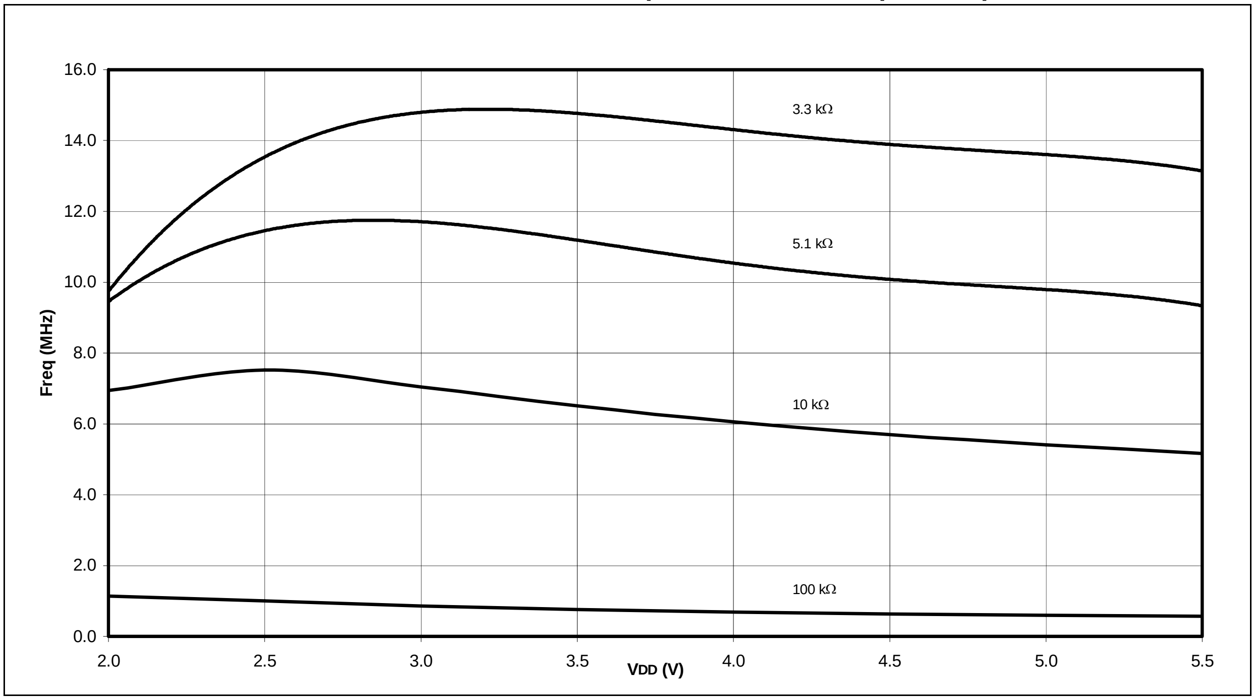


FIGURE 10-8: AVERAGE FOSC vs. VDD FOR R (RC MODE, C = 100 pF, 25°C)

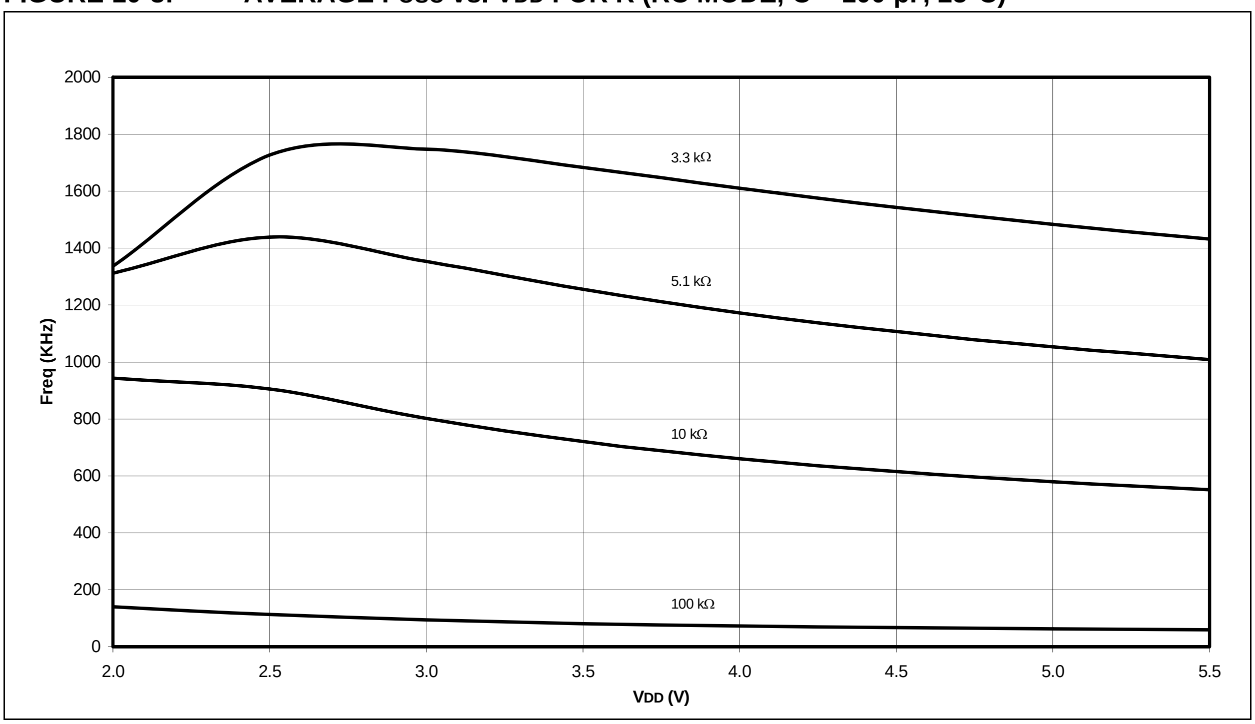


TABLE 1: CONVERSION CONSIDERATIONS - PIC16C84, PIC16F83/F84, PIC16CR83/CR84, PIC16F84A (CONTINUED)

Difference	PIC16C84	PIC16F83/F84	PIC16CR83/ CR84	PIC16F84A
EEADR<7:6> and I_{DD}	It is recommended that the EEADR<7:6> bits be cleared. When either of these bits is set, the maximum I_{DD} for the device is higher than when both are cleared.	N/A	N/A	N/A
The polarity of the $\overline{\text{PWRTE}}$ bit	PWRTE	$\overline{\text{PWRTE}}$	$\overline{\text{PWRTE}}$	$\overline{\text{PWRTE}}$
Recommended value of R_{EXT} for RC oscillator circuits	$R_{EXT} = 3k\Omega - 100k\Omega$	$R_{EXT} = 5k\Omega - 100k\Omega$	$R_{EXT} = 5k\Omega - 100k\Omega$	$R_{EXT} = 3k\Omega - 100k\Omega$
GIE bit unintentional enable	If an interrupt occurs while the Global Interrupt Enable (GIE) bit is being cleared, the GIE bit may unintentionally be re-enabled by the user's Interrupt Service Routine (the `RETFIE` instruction).	N/A	N/A	N/A
Packages	PDIP, SOIC	PDIP, SOIC	PDIP, SOIC	PDIP, SOIC, SSOP
Open Drain High Voltage (V_{OD})	14V	12V	12V	8.5V

APPENDIX C: MIGRATION FROM BASELINE TO MID-RANGE DEVICES

This section discusses how to migrate from a baseline device (i.e., PIC16C5X) to a mid-range device (i.e., PIC16CXXX).

The following is the list of feature improvements over the PIC16C5X microcontroller family:

1. Instruction word length is increased to 14-bits. This allows larger page sizes, both in program memory (2K now as opposed to 512K before) and the register file (128 bytes now versus 32 bytes before).
2. A PC latch register (PCLATH) is added to handle program memory paging. PA2, PA1 and PA0 bits are removed from the STATUS register and placed in the OPTION register.
3. Data memory paging is redefined slightly. The STATUS register is modified.
4. Four new instructions have been added: `RETURN`, `RETFIE`, `ADDLW`, and `SUBLW`. Two instructions, `TRIS` and `OPTION`, are being phased out, although they are kept for compatibility with PIC16C5X.
5. OPTION and TRIS registers are made addressable.
6. Interrupt capability is added. Interrupt vector is at 0004h.
7. Stack size is increased to eight-deep.
8. RESET vector is changed to 0000h.
9. RESET of all registers is revisited. Five different RESET (and wake-up) types are recognized. Registers are reset differently.
10. Wake-up from SLEEP through interrupt is added.
11. Two separate timers, the Oscillator Start-up Timer (OST) and Power-up Timer (PWRT), are included for more reliable power-up. These timers are invoked selectively to avoid unnecessary delays on power-up and wake-up.
12. PORTB has weak pull-ups and interrupt-on-change features.
13. T0CKI pin is also a port pin (RA4/T0CKI).
14. FSR is a full 8-bit register.
15. "In system programming" is made possible. The user can program PIC16CXX devices using only five pins: V_{DD}, V_{SS}, V_{PP}, RB6 (clock) and RB7 (data in/out).

To convert code written for PIC16C5X to PIC16F84A, the user should take the following steps:

1. Remove any program memory page select operations (PA2, PA1, PA0 bits) for `CALL`, `GOTO`.
2. Revisit any computed jump operations (write to PC or add to PC, etc.) to make sure page bits are set properly under the new scheme.
3. Eliminate any data memory page switching. Redefine data variables for reallocation.
4. Verify all writes to STATUS, OPTION, and FSR registers since these have changed.
5. Change RESET vector to 0000h.

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